NSN 5961-01-016-8849

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View Online at https://aerobasegroup.com/nsn/5961-01-016-8849 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6323 professional/industrial association specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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